

# FSL206MRBN

## Green Mode Fairchild Power Switch (FPS™)

### Features

- Internal Avalanche-Rugged SenseFET: 650V
- Precision Fixed Operating Frequency: 67kHz
- No-Load <150mW at 265V<sub>AC</sub> without Bias
- Winding; <30mW with Bias Winding
- No Need for Auxiliary Bias Winding
- Frequency Modulation for Attenuating EMI
- Line Under-Voltage Protection (LUVF)
- Pulse-by-Pulse Current Limiting
- Low Under-Voltage Lockout (UVLO)
- Ultra-Low Operating Current: 300µA
- Built-In Soft-Start and Startup Circuit
- Various Protections: Overload Protection (OLP), Over-Voltage Protection (OVP), Thermal Shutdown (TSD), Abnormal Over-Current Protection (AOCP) Auto-Restart Mode for All Protections

### Applications

- SMPS for STB, DVD, and DVCD Player
- SMPS for Auxiliary Power

### Related Resources

- [Fairchild Power Supply WebDesigner — Flyback Design & Simulation - In Minutes at No Expense](#)
- [AN-4137 — Design Guidelines for Offline Flyback Converters Using FPS™](#)
- [AN-4141 — Troubleshooting and Design Tips for Fairchild Power Switch \(FPS™\) Flyback Applications](#)
- [AN-4147 — Design Guidelines for RCD Snubber of Flyback](#)
- [AN-4150 — Design Guidelines for Flyback Converters Using FSQ-Series Fairchild Power Switch \(FPS™\)](#)

### Description

The FSL206MRBN integrated Pulse-Width Modulator (PWM) and SenseFET is specifically designed for high-performance offline Switched-Mode Power Supplies (SMPS) with minimal external components. This device integrates high-voltage power regulators that combine an avalanche-rugged SenseFET with a Current-Mode PWM control block.

The integrated PWM controller includes: 7.8V regulator for no bias winding, Under-Voltage Lockout (UVLO) protection, Leading-Edge Blanking (LEB), an optimized gate turn-on/turn-off driver, EMI attenuator, Thermal Shutdown (TSD) protection, temperature-compensated precision current sources for loop compensation, and fault-protection circuitry such as Overload Protection (OLP), Over-Voltage Protection (OVP), Abnormal Over-Current Protection (AOCP), and Line Under-Voltage Protection (LUVF). During startup, the FSL206MRBN offers good soft-start performance.

The internal high-voltage startup switch and the Burst-Mode operation with very low operating current reduce the power loss in Standby Mode. As a result, it is possible to reach power loss of 150mW with no-bias winding and 30mW with bias winding at no-load condition when the input voltage is 265V<sub>AC</sub>.

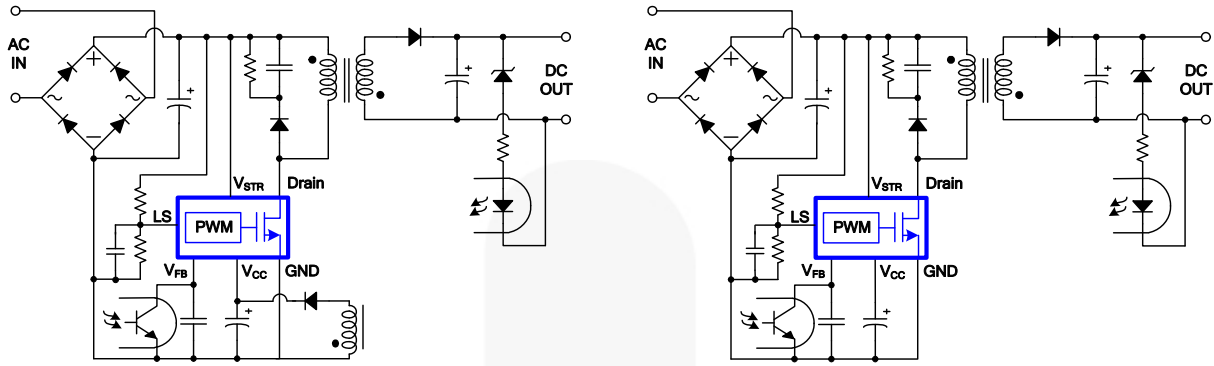
### Ordering Information

Part Number	Operating Temperature	Top Mark	PKG	Packing Method	Output Power Table <sup>(1)</sup>			
					Current Limit	R <sub>DS(ON),MAX</sub>	230V <sub>AC</sub> <sup>(2)</sup>	85 ~ 265V <sub>AC</sub>
							±15% <sup>(2)</sup>	Open Frame <sup>(3)</sup>
FSL206MRBN	-40 ~ 115°C	L206MRB	8-DIP	Rail	0.6A	19Ω	12W	7W

#### Notes:

1. The junction temperature can limit the maximum output power.
2. 230V<sub>AC</sub> or 100/115V<sub>AC</sub> with doubler. The maximum power with CCM operation.
3. Maximum practical continuous power in an open-frame design at 50°C ambient.

### Application Diagram



(a) With Bias Winding

(b) Without Bias Winding

Figure 22. Typical Application

### Internal Block Diagram

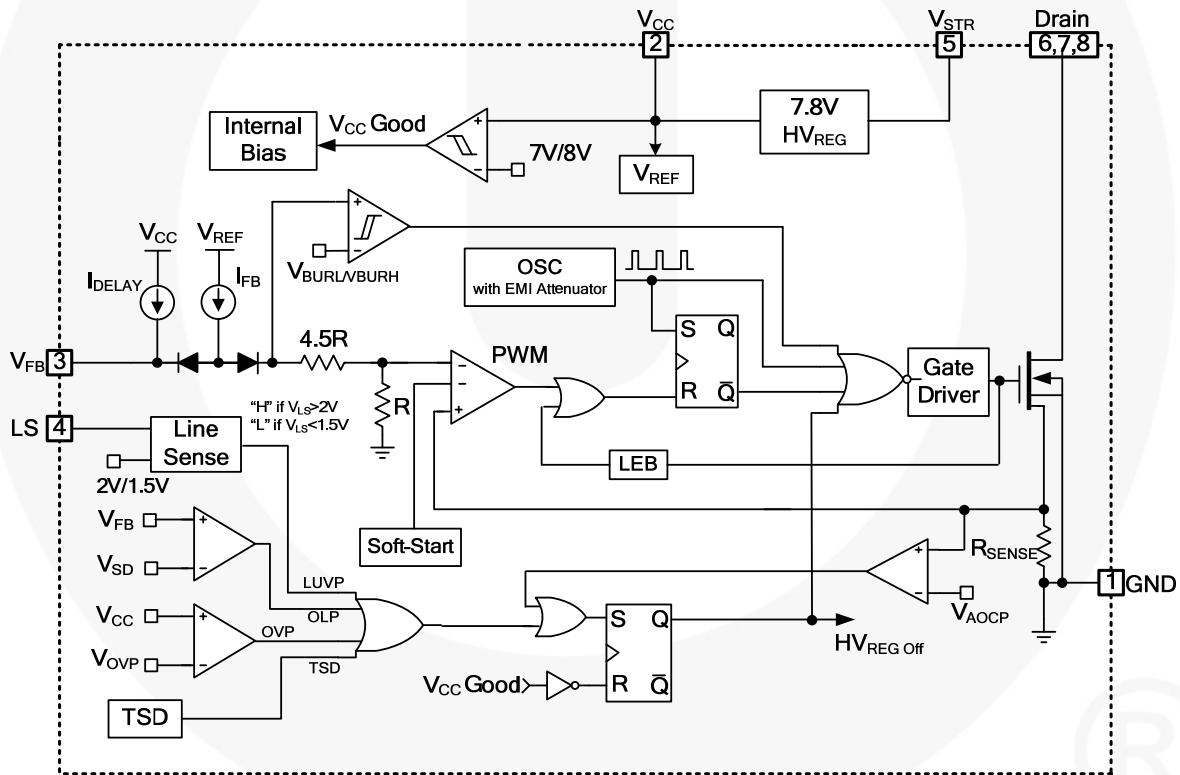


Figure 23. Internal Block Diagram

## Pin Configuration

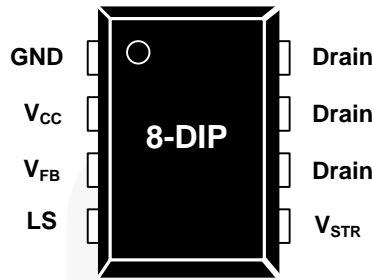


Figure 24. Pin Configuration

## Pin Definitions

Pin #	Name	Description
1	GND	<b>Ground.</b> SenseFET source terminal on primary side and internal control ground.
2	V <sub>CC</sub>	<b>Positive Supply Voltage Input.</b> Although connected to an auxiliary transformer winding, current is supplied from pin 5 (V <sub>STR</sub> ) via an internal switch during startup ( <i>see Internal Block Diagram section</i> ). It is not until V <sub>CC</sub> reaches the UVLO upper threshold (8V) that the internal startup switch opens and device power is supplied via the auxiliary transformer winding.
3	V <sub>FB</sub>	<b>Feedback Voltage.</b> Non-inverting input to the PWM comparator, with a 0.11mA current source connected internally and a capacitor and opto-coupler typically connected externally. There is a delay while charging external capacitor C <sub>FB</sub> from 2.4V to 5V using an internal 2.7μA current source. This delay prevents false triggering under transient conditions, but allows the protection mechanism to operate under true overload conditions.
4	LS	<b>Line Sense Pin.</b> This pin is used to protect the device when the input voltage is lower than the rated input voltage range. If this pin is not used, connect to ground.
5	V <sub>STR</sub>	<b>Startup.</b> Connected to the rectified AC line voltage source. At startup, the internal switch supplies internal bias and charges an external storage capacitor placed between the V <sub>CC</sub> pin and ground. Once V <sub>CC</sub> reaches 8V, all internal blocks are activated. After that, the internal high-voltage regulator (HV REG) turns on and off irregularly to maintain V <sub>CC</sub> at 7.8V.
6, 7, 8	Drain	<b>Drain.</b> Designed to connect directly to the primary lead of the transformer and capable of switching a maximum of 650V. Minimizing the length of the trace connecting these pins to the transformer decreases leakage inductance.

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.  $T_A = 25^\circ\text{C}$  unless otherwise specified.

Symbol	Parameter	Min.	Max.	Unit
$V_{STR}$	$V_{STR}$ Pin Voltage	-0.3	650.0	V
$V_{DS}$	Drain Pin Voltage	-0.3	650.0	V
$V_{CC}$	Supply Voltage		26	V
$V_{LS}$	LS Pin Voltage	-0.3	Internally Clamped Voltage <sup>(4)</sup>	V
$V_{FB}$	Feedback Voltage Range	-0.3	Internally Clamped Voltage <sup>(4)</sup>	V
$I_{DM}$	Drain Current Pulsed <sup>(5)</sup>		1.5	A
$E_{AS}$	Single-Pulsed Avalanche Energy <sup>(6)</sup>		11	mJ
$P_D$	Total Power Dissipation		1.3	W
$T_J$	Operating Junction Temperature	-40	+150	$^\circ\text{C}$
$T_A$	Operating Ambient Temperature	-40	+125	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	-55	+150	$^\circ\text{C}$
ESD	Human Body Model, JESD22-A114		4	KV
	Charged Device Model, JESD22-C101		2	

### Notes:

- $V_{FB}$  is clamped by internal clamping diode ( $13\text{V } I_{CLAMP\_MAX} < 100\mu\text{A}$ ). After shutdown, before  $V_{CC}$  reaching  $V_{STOP}$ ,  $V_{SD} < V_{FB} < V_{CC}$ .
- Repetitive rating: pulse-width limited by maximum junction temperature.
- $L=21\text{mH}$ , starting  $T_J=25^\circ\text{C}$ .

## Thermal Impedance

$T_A=25^\circ\text{C}$  unless otherwise specified.

Symbol	Parameter	Value	Unit
$\theta_{JA}$	Junction-to-Ambient Thermal Impedance <sup>(7)</sup>	93	$^\circ\text{C/W}$

### Notes:

- JEDEC recommended environment, JESD51-2, bv and test board, JESD51-10, with minimum land pattern.

## Electrical Characteristics

$T_A = 25^\circ\text{C}$  unless otherwise specified.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
<b>SenseFET Section</b>						
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{CC} = 0V, I_D = 250\mu A$	650			V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 650V, V_{GS} = 0V$			50	$\mu A$
		$V_{DS} = 520V, V_{GS} = 0V, T_A = 125^\circ\text{C}^{(8)}$			250	$\mu A$
$R_{DS(ON)}$	Drain-Source On-State Resistance <sup>(9)</sup>	$V_{GS} = 10V, I_D = 0.3A$		14	19	$\Omega$
$C_{ISS}$	Input Capacitances	$V_{GS} = 0V, V_{DS} = 25V, f = 1\text{MHz}$		162		pF
$C_{OSS}$	Output Capacitance	$V_{GS} = 0V, V_{DS} = 25V, f = 1\text{MHz}$		14.9		pF
$C_{RSS}$	Reverse Transfer Capacitance	$V_{GS} = 0V, V_{DS} = 25V, f = 1\text{MHz}$		2.7		pF
$t_r$	Rise Time	$V_{DS} = 325V, I_D = 0.5A, R_G = 25\Omega$		6.1		ns
$t_f$	Fall Time	$V_{DS} = 325V, I_D = 0.5A, R_G = 25\Omega$		43.6		ns
<b>Control Section</b>						
$f_{OSC}$	Switching Frequency	$V_{FB} = 4V, V_{CC} = 10V$	61	67	73	KHz
$\Delta f_{OSC}$	Switching Frequency Variation	$-25^\circ\text{C} < T_J < 85^\circ\text{C}$		$\pm 5$	$\pm 10$	%
$f_M$	Frequency Modulation <sup>(8)</sup>			$\pm 3$		KHz
$D_{MAX}$	Maximum Duty Cycle	$V_{FB} = 4V, V_{CC} = 10V$	66	72	78	%
$D_{MIN}$	Minimum Duty Cycle	$V_{FB} = 0V, V_{CC} = 10V$	0	0	0	%
$V_{START}$	UVLO Threshold Voltage	$V_{FB} = 0V, V_{CC}$ Sweep	7	8	9	V
$V_{STOP}$		After Turn On	6	7	8	V
$I_{FB}$	Feedback Source Current	$V_{FB} = 0V, V_{CC} = 10V$	90	110	130	$\mu A$
$t_{S/S}$	Internal Soft-Start Time	$V_{FB} = 4V, V_{CC} = 10V$	10	15	20	ms
<b>Burst Mode Section</b>						
$V_{BURH}$	Burst-Mode HIGH Threshold Voltage	$V_{CC} = 10V, V_{FB}$ Increase	0.4	0.5	0.6	V
$V_{BURL}$	Burst-Mode LOW Threshold Voltage	$V_{CC} = 10V, V_{FB}$ Decrease	0.28	0.35	0.42	V
$HYS_{BUR}$	Burst-Mode Hysteresis			150		mV
<b>Protection Section</b>						
$I_{LIM}$	Peak Current Limit	$V_{FB} = 4V, di/dt = 300\text{mA}/\mu\text{s}, V_{CC} = 10V$	0.54	0.60	0.66	A
$t_{CLD}$	Current Limit Delay <sup>(8)</sup>			100		ns
$V_{SD}$	Shutdown Feedback Voltage	$V_{CC} = 10V$	4.5	5.0	5.5	V
$I_{DELAY}$	Shutdown Delay Current	$V_{FB} = 4V$	2.1	2.7	3.3	$\mu A$
$t_{LEB}$	Leading-Edge Blanking Time <sup>(8)</sup>		250			ns
$V_{AOCP}$	Abnormal Over-Current Protection <sup>(8)</sup>			0.7		V
$V_{OVP}$	Over-Voltage Protection	$V_{FB} = 4V, V_{CC}$ Increase	23.0	24.5	26.0	V
$V_{LS\_OFF}$	Line-Sense Protection On to Off	$V_{FB} = 3V, V_{CC} = 10V, V_{LS}$ Decrease	1.9	2.0	2.1	V
$V_{LS\_ON}$	Line-Sense Protection Off to On	$V_{FB} = 3V, V_{CC} = 10V, V_{LS}$ Increase	1.4	1.5	1.6	V
TSD	Thermal Shutdown Temperature <sup>(8)</sup>		+125	+135	+150	$^\circ\text{C}$
$HYS_{TSD}$	TSD Hysteresis Temperature <sup>(8)</sup>			+60		$^\circ\text{C}$

Continued on the following page...

**Electrical Characteristics** (Continued)T<sub>A</sub> = 25°C unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
<b>High Voltage Regulator Section</b>						
V <sub>HVR</sub>	HV Regulator Voltage	V <sub>FB</sub> = 0V, V <sub>STR</sub> = 40V		7.8		V
<b>Total Device Section</b>						
I <sub>OP1</sub>	Operating Supply Current (Control Part Only, without Switching)	V <sub>CC</sub> = 15V, 0V < V <sub>FB</sub> < V <sub>BURL</sub>		0.3	0.5	mA
I <sub>OP2</sub>	Operating Supply Current (Control Part Only, without Switching)	V <sub>CC</sub> = 8V, 0V < V <sub>FB</sub> < V <sub>BURL</sub>		0.25	0.45	mA
I <sub>OP3</sub>	Operating Supply Current <sup>(8)</sup> (While Switching)	V <sub>CC</sub> = 15V, V <sub>BURL</sub> < V <sub>FB</sub> < V <sub>SD</sub>			1.3	mA
I <sub>CH</sub>	Startup Charging Current	V <sub>CC</sub> = 0V, V <sub>STR</sub> > 40V	1.6	1.9	2.2	mA
I <sub>START</sub>	Startup Current	V <sub>CC</sub> = Before V <sub>START</sub> , V <sub>FB</sub> = 0V		100	150	μA
V <sub>STR</sub>	Minimum V <sub>STR</sub> Supply Voltage	V <sub>CC</sub> = V <sub>FB</sub> = 0V, V <sub>STR</sub> Increase		26		V

**Notes:**

8. Though guaranteed by design, not 100% tested in production.
9. Pulse test: pulse width=300ms, duty cycle=2%.

## Typical Performance Characteristics

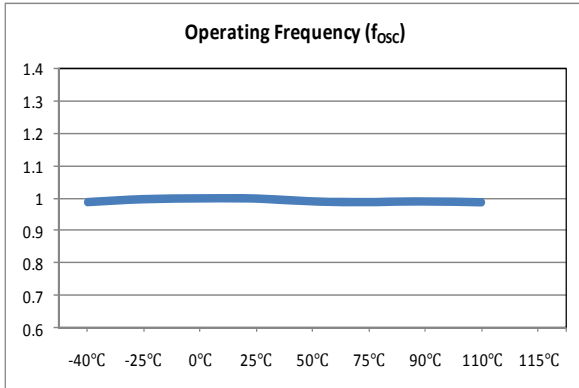


Figure 25. Operating Frequency vs. Temperature

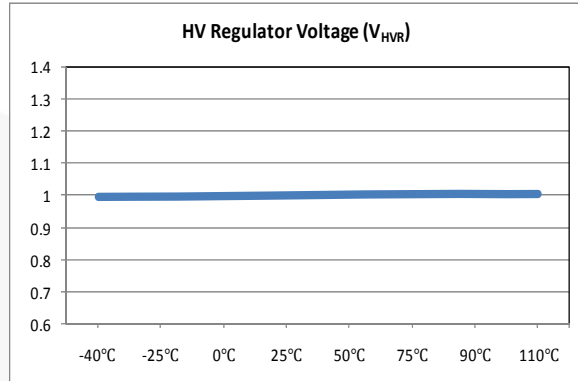


Figure 26. HV Regulator Voltage vs. Temperature

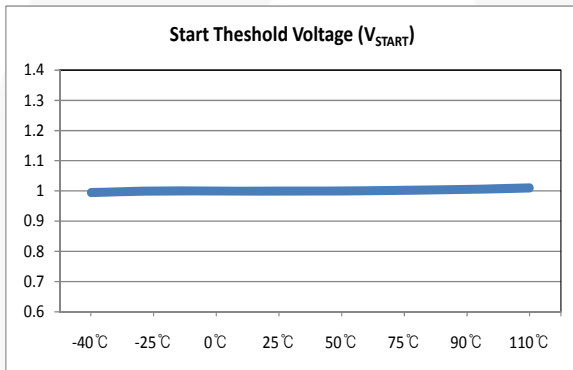


Figure 27. Start Threshold Voltage vs. Temperature

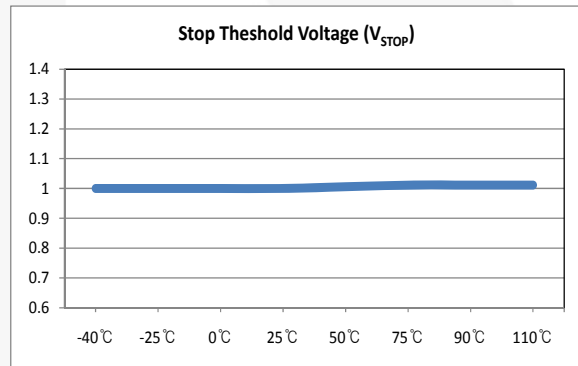


Figure 28. Stop Threshold Voltage vs. Temperature

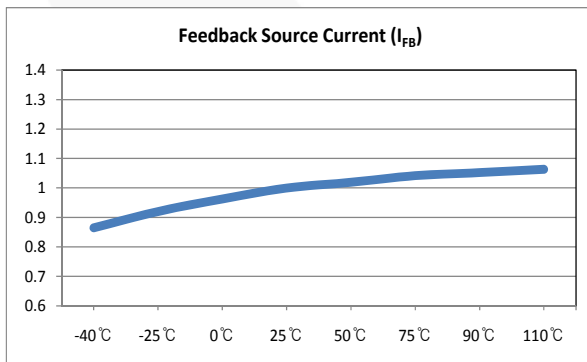


Figure 29. Feedback Source Current vs. Temperature

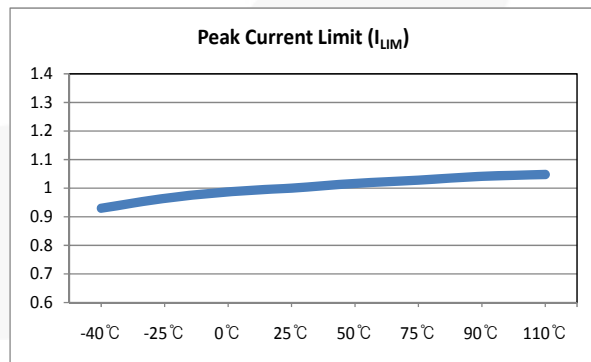
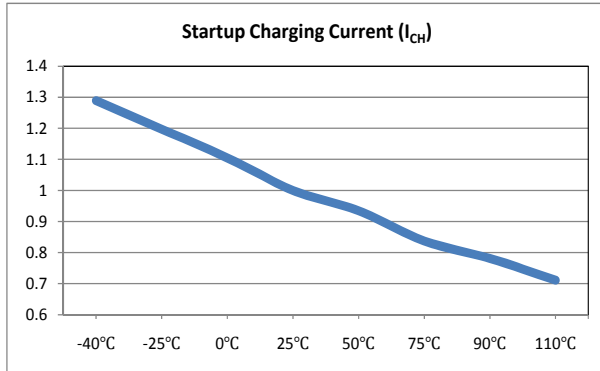
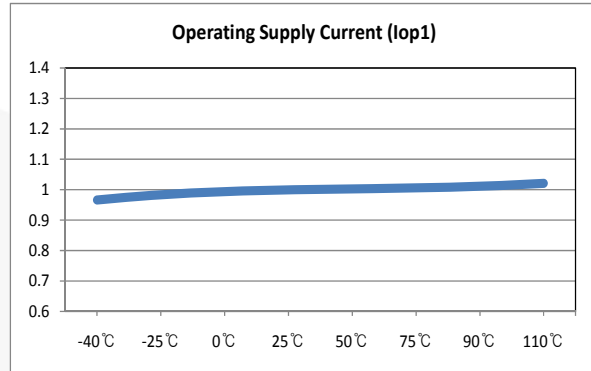


Figure 30. Peak Current Limit vs. Temperature

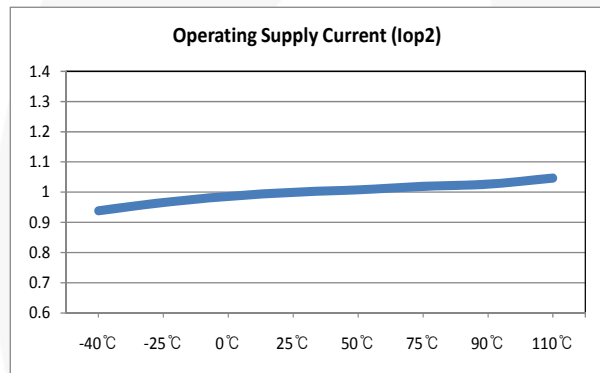
**Typical Performance Characteristics (Continued)**



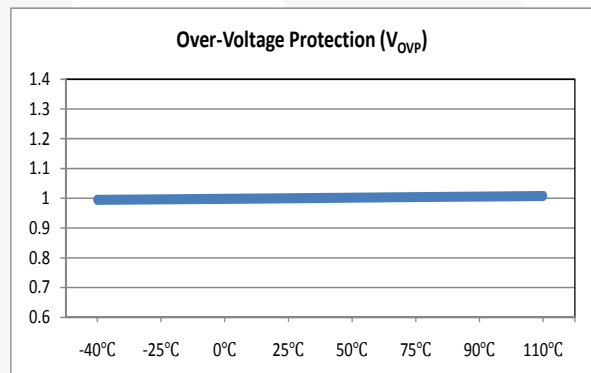
**Figure 31. Startup Charging Current vs. Temperature**



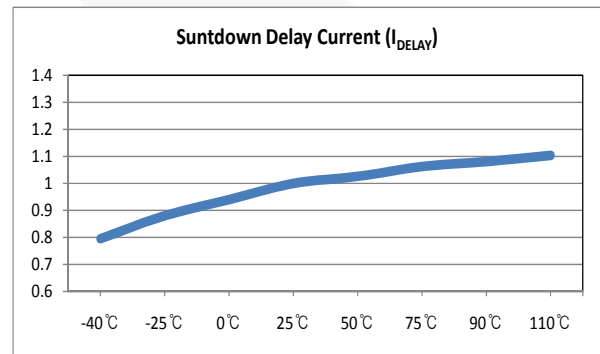
**Figure 32. Operating Supply Current 1 vs. Temperature**



**Figure 33. Operating Supply Current 2 vs. Temperature**



**Figure 34. Over-Voltage Protection Voltage vs. Temperature**



**Figure 35. Shutdown Delay Current vs. Temperature**



## Functional Description

### Startup

At startup, an internal high-voltage current source supplies the internal bias and charges the external capacitor ( $C_A$ ) connected to the  $V_{CC}$  pin, as illustrated in Figure 36. An internal high-voltage regulator (HV REG) located between the  $V_{STR}$  and  $V_{CC}$  pins regulates the  $V_{CC}$  to 7.8V and supplies operating current. Therefore, FSL206MRBN needs no auxiliary bias winding.

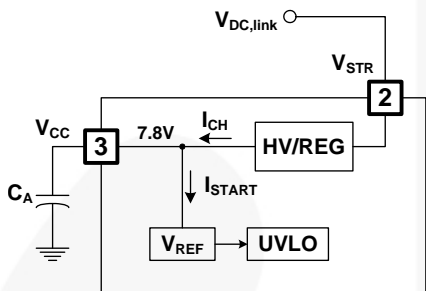


Figure 36. Startup Block

### Oscillator Block

The oscillator frequency is set internally and the FPS™ has a random frequency fluctuation function.

Fluctuation of the switching frequency can reduce EMI by spreading the energy over a wider frequency range than the bandwidth measured by the EMI test equipment. The amount of EMI reduction is directly related to the range of the frequency variation. The range of frequency variation is fixed internally; however, its selection is randomly chosen by the combination of an external feedback voltage and internal free-running oscillator. This randomly chosen switching frequency effectively spreads the EMI noise near switching frequency and allows the use of a cost-effective inductor instead of an AC input line filter to satisfy world-wide EMI requirements.

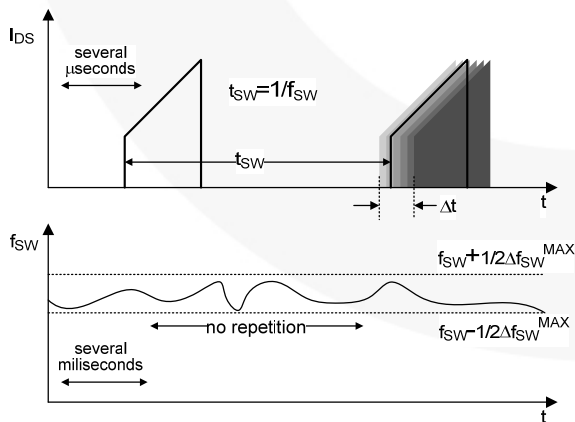


Figure 37. Frequency Fluctuation Waveform

### Feedback Control

FSL206MRBN employs Current-Mode control, as shown in Figure 38. An opto-coupler (such as the FOD817A) and shunt regulator (such as the KA431) are typically used to implement the feedback network. Comparing the feedback voltage with the voltage across the  $R_{SENSE}$  resistor makes it possible to control the switching duty cycle. When the shunt regulator reference pin voltage exceeds the internal reference voltage of 2.5V; the opto-coupler LED current increases, feedback voltage  $V_{FB}$  is pulled down, and the duty cycle is reduced. This typically occurs when input voltage is increased or output load is decreased.

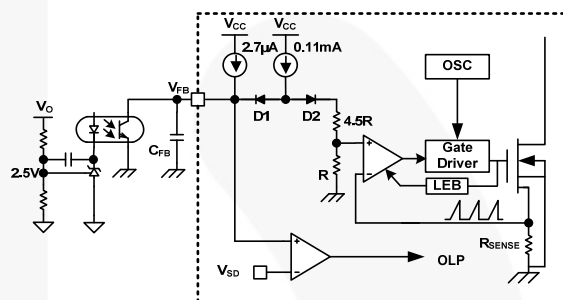


Figure 38. Pulse-Width-Modulation (PWM) Circuit

### Leading-Edge Blanking (LEB)

At the instant the internal SenseFET is turned on, the primary-side capacitance and secondary-side rectifier diode reverse recovery typically cause a high-current spike through the SenseFET. Excessive voltage across the  $R_{SENSE}$  resistor leads to incorrect feedback operation in the Current-Mode PWM control. To counter this effect, the FPS employs a leading-edge blanking (LEB) circuit (see Figure 38). This circuit inhibits the PWM comparator for a short time ( $t_{LEB}$ ) after the SenseFET is turned on.

### Protection Circuits

The protective functions include Overload Protection (OLP), Over-Voltage Protection (OVP), Under-Voltage Lockout (UVLO), Line Under-Voltage Protection (LUV), Abnormal Over-Current Protection (AOCP), and thermal shutdown (TSD). Because these protection circuits are fully integrated inside the IC without external components, reliability is improved without increasing cost. Once a fault condition occurs, switching is terminated and the SenseFET remains off. This causes  $V_{CC}$  to fall. When  $V_{CC}$  reaches the UVLO stop voltage  $V_{STOP}$  (7V), the protection is reset and the internal high-voltage current source charges the  $V_{CC}$  capacitor via the  $V_{STR}$  pin. When  $V_{CC}$  reaches the UVLO start voltage  $V_{START}$  (8V), the FPS resumes normal operation. In this manner, auto-restart can alternately enable and disable the switching of the power SenseFET until the fault condition is eliminated.



### Line Under-Voltage Protection (LUVP)

If the input voltage of the converter is lower than the minimum operating voltage, the converter input current increases too much, causing components failure. If the input voltage is low, the converter should be protected. In the FSL206MRBN, the LUVP circuit senses the input voltage using the LS pin and, if this voltage is lower than 1.5V, the LUVP signal is generated. The comparator has 0.5V hysteresis. If the LUVP signal is generated, the output drive block is shut down and the output voltage feedback loop is saturated.

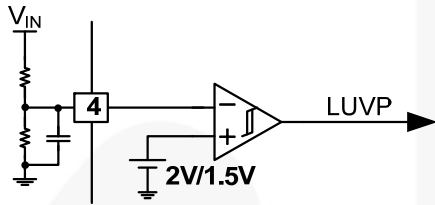


Figure 42. Line UVP Circuit

### Soft-Start

The FSL206MRBN has an internal soft-start circuit that slowly increases the feedback voltage, together with the SenseFET current, after it starts. The typical soft-start time is 15ms, as shown in Figure 43, where progressive increments of the SenseFET current are allowed during the startup phase. The pulse width to the power switching device is progressively increased to establish the correct working conditions for transformers, inductors, and capacitors. The voltage on the output capacitors is progressively increased with the intention of smoothly establishing the required output voltage. It also helps prevent transformer saturation and reduce the stress on the secondary diode.

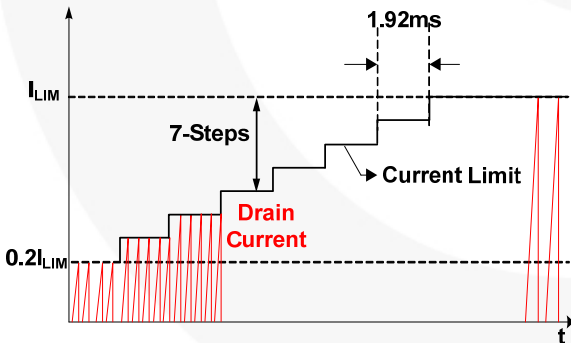


Figure 43. Internal Soft-Start

### Burst Operation

To minimize power dissipation in Standby Mode, the FPS enters Burst Mode. As the load decreases, the feedback voltage decreases. As shown in Figure 44, the device automatically enters Burst Mode when the feedback voltage drops below  $V_{BURH}$ . Switching continues until the feedback voltage drops below  $V_{BURL}$ . At this point, switching stops and the output voltages start to drop at a rate dependent on the standby current load. This causes the feedback voltage to rise. Once it passes  $V_{BURH}$ , switching resumes. The feedback voltage then falls and the process repeats. Burst Mode alternately enables and disables switching of the SenseFET and reduces switching loss in Standby Mode.

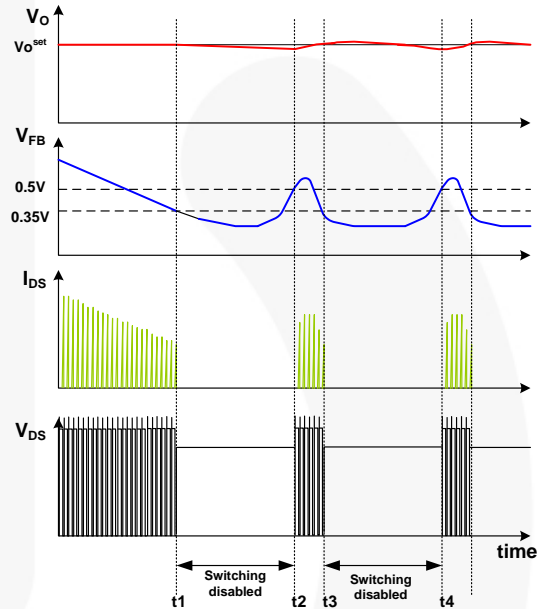
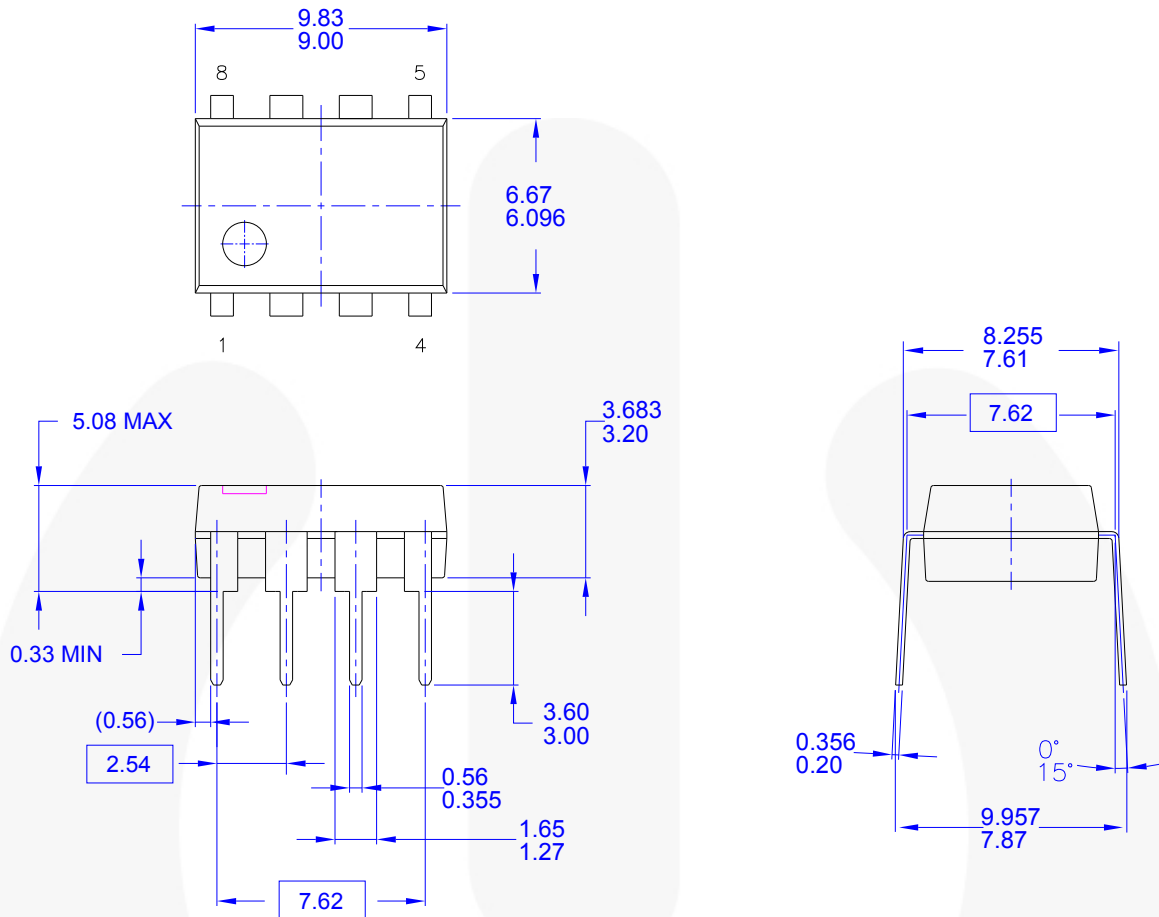


Figure 44. Burst-Mode Operation

## Physical Dimensions



### NOTES: UNLESS OTHERWISE SPECIFIED

- A) THIS PACKAGE CONFORMS TO JEDEC MS-001 VARIATION BA
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- D) DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994
- E) DRAWING FILENAME AND REVISION: MKT-N08FREV2.

**Figure 45. 8-Lead, Dual In-Line Package (DIP)**





Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

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<http://www.fairchildsemi.com/packaging/>



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| 2Cool™   | F-PFS™   | PowerTrench®   | The Power Franchise®   |
| AccuPower™   | FRFET®   | PowerXS™   | the power franchise  |
| AX-CAP™*   | Global Power Resource™                         | Programmable Active Droop™   | TinyBoost™   |
| BitSiC™  | GreenBridge™                                   | QFET®  | TinyBuck™  |
| Build it Now™  | Green FPS™                                     | QS™  | TinyCalc™  |
| CorePLUS™  | Green FPS™ e-Series™                           | Quiet Series™  | TinyLogic®   |
| CorePOWER™   | Gmax™  | RapidConfigure™  | TINYOPTO™  |
| CROSSVOLT™   | GTO™   |  ™                | TinyPower™   |
| CTL™   | IntelliMAX™                                    | Saving our world, 1mW/WkW at a time™   | TinyPWM™   |
| Current Transfer Logic™  | ISOPLANAR™                                     | SignalWise™  | TinyWire™  |
| DEUXPEED®  | Making Small Speakers Sound Louder and Better™ | SmartMax™  | TranSiC™   |
| Dual Cool™   | MegaBuck™                                      | SMART START™   | TriFault Detect™   |
| EcoSPARK®  | MICROCOUPLER™                                  | Solutions for Your Success™  | TRUECURRENT®*  |
| EfficientMax™  | MicroFET™                                      | SPM®   | µSerDes™   |
| ESBC™  | MicroPak™                                      | STEALTH™   |  SerDes |
|  Fairchild® | MicroPak2™                                     | SuperFET®  | UHC®   |
| Fairchild Semiconductor®   | MillerDrive™                                   | SuperSOT™-3  | Ultra FRFET™   |
| FACT Quiet Series™   | MotionMax™                                     | SuperSOT™-6  | UniFET™  |
| FACT®  | Motion-SPM™                                    | SuperSOT™-8  | VCX™   |
| FAST®  | mWSaver™                                       | SupreMOS®  | VisualMax™   |
| FastvCore™   | OptoHIT™                                       | SyncFET™   | VoltagePlus™   |
| FETBench™  | OPTOLOGIC®                                     | Sync-Lock™   | XS™  |
| FlashWriter®*  | OPTOPLANAR®                                    |  SYSTEM GENERAL®* |  |
| FPS™   |  |  |  |

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**PRODUCT STATUS DEFINITIONS**

**Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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Rev. I61